

	<p>Hersteller-Teilenummer: SIHU3N50D-E3</p>
	<p>Hersteller / Marke: Vishay / Siliconix</p>
	<p>Teil der Beschreibung: MOSFET N-CH 500V 3A TO251 IPAK</p>
	<p>Datenblätter:  SIHU3N50D-E3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 5000 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHU3N50D-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 500V 3A TO251 IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	TO-251AA
Verlustleistung (max)	69W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3A (Tc)
Rds On (Max) @ Id, Vgs	3.2 Ohm @ 2.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	175pF @ 100V
Verpackung	Tube



















































SIHU3N50D-E3 ist neu im Original, Suche SIHU3N50D-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHU3N50D-E3 Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage SIHU3N50D-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHS90N65E-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 650V 87A SUPER247</p>	 <p>SIHU3N50D-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 3A TO251 IPAK</p>	 <p>SIHU2N80E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 800V 2.8A IPAK</p>	 <p>SIHU5N50D-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 5.3A TO251 IPAK</p>
 <p>SIHU3N50D-GE3 Vishay / Siliconix MOSFET N-CH 500V 3A TO251 IPAK</p>	 <p>SIHS90N65E-E3 Vishay / Siliconix MOSFET N-CH 650V 87A SUPER247</p>	 <p>SIHU3N50D-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 3A TO251 IPAK</p>	 <p>SIHU4N80E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 800V TO-251 IPAK</p>

heiße Teile

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|  SIHFSL11N50A |  SIHG16N50C-E3 |  SIHG16N50C-E3 |  SIHG17N60D |  SIHG20N50C |
|  SIHG22N60S-E3 |  SIHG30N60E |  SIHG33N60E |  SIHG47N60E-E3 |  SIHG47N60E-E3 |
|  SIHG47N60E-GE3 |  SIHG47N60E-GE3 |  SIHG47N60S-E3 |  SIHG70N60EFEF-GE3 |  SIHG73N60E-GE3 |
|  SIHG73N60E-GE3 |  SIHP10N40D |  SIHP12N50C-E3 |  SIHP12N50C-E3 |  SIHP12N60E-E3 |
|  SIHP12N60E-E3 |  SIHP12N60E-GE3 |  SIHP12N60E-GE3 |  SIHP12N65E |  SIHP14N50D |
|  SIHP15N60E-E3 |  SIHP15N60E-E3 |  SIHP15N65E |  SIHP16N50C-E3 |  SIHP16N50C-E3 |
|  SIHP17N60D-E3 |  SIHP17N60D-E3 |  SIHP18N50C-E3 |  SIHP18N50C-E3 |  SIHP22N60S-E3 |
|  SIHP30N60E-E3 |  SIHP30N60E-E3 |  SIHP30N60E-GE3 |  SIHP30N60E-GE3 |  SIHP30N60E-GE3 |
|  SIHP33N60E-GE3 |  SIHP33N60E-GE3 |  SIHP5N50D-E3 |  SIHP5N50D-E3 |  SIHP6N40D |
|  SIHP8N50D-E3 |  SIHP8N50D-E3 |  SIHU3N50D-E3 |  SIHW30N60E-GE3 |  SIHW30N60E-GE3 |

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